



100V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)}	I _D Tc = +25°C
1001/	32mΩ @ V _{GS} = 10V	33A
100V	50mΩ @ V _{GS} = 4.5V	26A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Synchronous rectifiers
- Backlighting
- Power management functions
- DC-DC converters

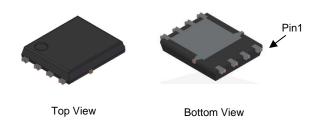
Features

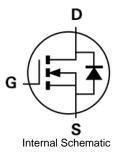
- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low Input Capacitance
- Fast Switching Speed
- Wettable Flank for Improved Optical Inspection
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

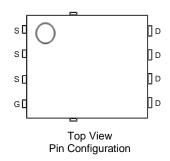
Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe;
 Solderable per MIL-STD-202, Method 208 ©3
- Weight: 0.097 grams (Approximate)

PowerDI5060-8 (SWP) (Type UX)







Ordering Information (Note 4)

Part Number	Pankaga	Packing		
Fait Number	Package	Qty.	Carrier	
DMTH10H032LPSW-13	PowerDI5060-8 (SWP) (Type UX)	2,500	Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



TH1032LSW = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 22 = 2022) WW = Week Code (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V _{DSS}	100	V
Gate-Source Voltage		Vgss	±20	V
Continuous Drain Current, V _{GS} = 10V (Note 5)	$T_C = +25$ °C $T_C = +100$ °C	lo	33 23	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	132	Α	
Maximum Continuous Body Diode Forward Current (Not	Is	33	Α	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		lsм	132	Α
Avalanche Current, L = 0.3mH (Note 6)		las	13	Α
Avalanche Energy, L = 0.3mH (Note 6)		E _{AS}	25.3	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 7) $T_A = +25^{\circ}C$		PD	3.4	W
Thermal Resistance, Junction to Ambient (Note 7)	Reja	44	°C/W	
Total Power Dissipation (Note 5)	P _D	68	W	
Thermal Resistance, Junction to Case (Note 5)	Rejc	2.2	°C/W	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes:

- 5. Thermal resistance from junction to soldering point (on the exposed drain pad).
- Ins and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.
 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

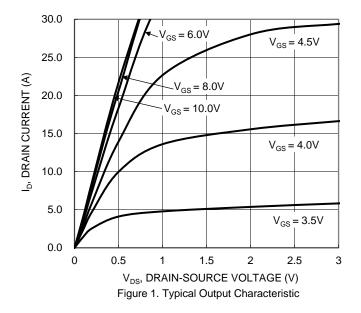
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	100	_	_	V	VGS = 0V, ID = 1mA	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μΑ	V _{DS} = 80V, V _{GS} = 0V	
Gate-Source Leakage	Igss	_	_	±100	nA	Vgs = ±20V, Vps = 0V	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	Vgs(TH)	1.3	_	2.5	V	V _{DS} = V _{GS} , I _D = 250μA	
Static Drain-Source On-Resistance	D	_	22	32	mΩ	$V_{GS} = 10V, I_D = 5A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	32	50	11177	$V_{GS} = 4.5V, I_D = 4.5A$	
Diode Forward Voltage	VsD	_	0.8	1	V	$V_{GS} = 0V$, $I_{S} = 5A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	_	683	_	pF	V _{DS} = 50V, V _{GS} = 0V f = 1MHz	
Output Capacitance	Coss	_	165	_	pF		
Reverse Transfer Capacitance	Crss	_	6.9	_	pF	1 = 1101112	
Gate Resistance	Rg	_	1.2	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	6.3	_	nC		
Total Gate Charge (Vgs = 10V)	Qg	_	11.9	_	nC	\/== F0\/ I= 6A	
Gate-Source Charge	Qgs	_	2.0	_	nC	V _{DS} = 50V, I _D = 6A	
Gate-Drain Charge	Q_{gd}	_	3.1	_	nC		
Turn-On Delay Time	tD(ON)	_	4.1	_	ns		
Turn-On Rise Time	t _R	_	4.5	_	ns	$V_{DS} = 50V, R_L = 5.85\Omega$ $V_{GS} = 10V, R_g = 3\Omega$	
Turn-Off Delay Time	tD(OFF)	_	12.5	_	ns		
Turn-Off Fall Time	t _F	_	9.3	_	ns		
Reverse Recovery Time	trr	_	31.5	_	ns	I _F = 6A, dI/dt = 500A/μs	
Reverse Recovery Charge	Qrr		94.6		nC		

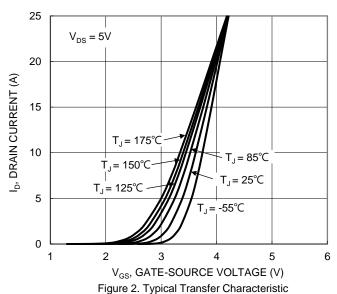
Notes:

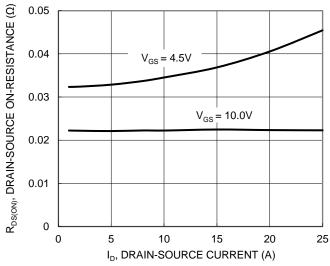
^{8.} Short duration pulse test used to minimize self-heating effect. 9. Guaranteed by design. Not subject to product testing.

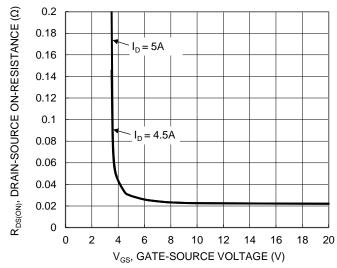












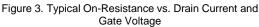
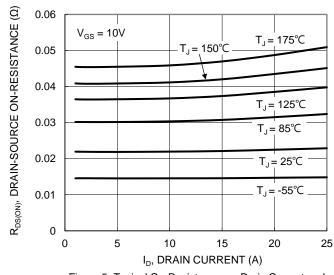


Figure 4. Typical Transfer Characteristic



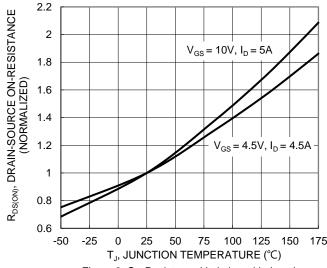


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

Figure 6. On-Resistance Variation with Junction Temperature



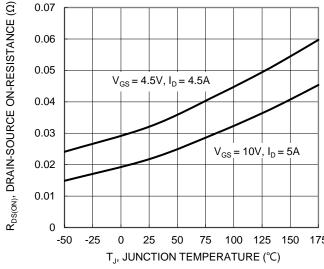
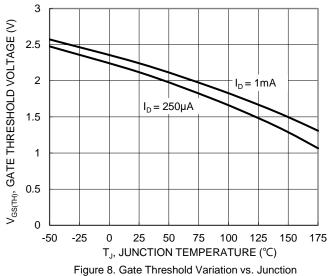


Figure 7. On-Resistance Variation with Junction Temperature



Temperature

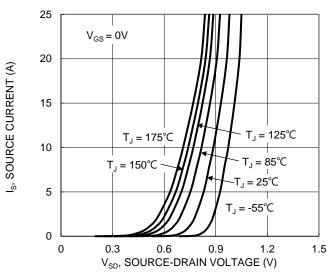


Figure 9. Diode Forward Voltage vs. Current

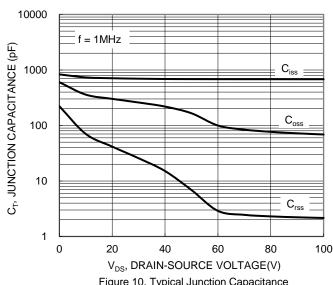


Figure 10. Typical Junction Capacitance

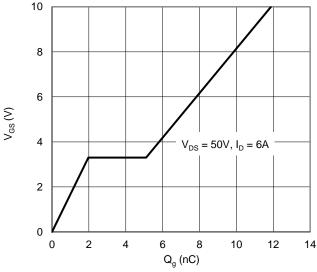


Figure 11. Gate Charge

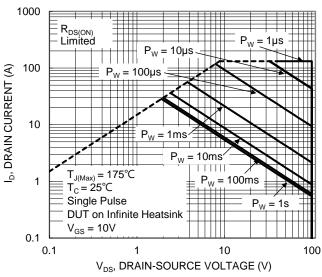


Figure 12. SOA, Safe Operation Area



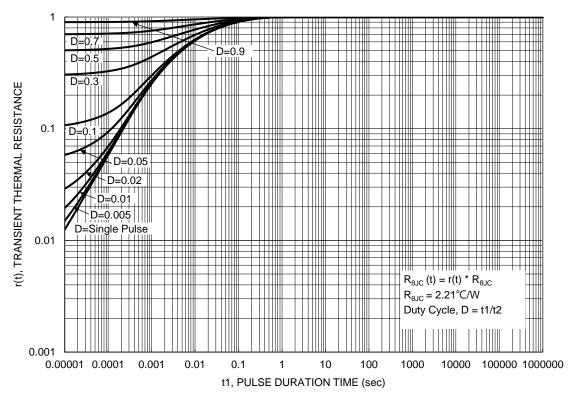


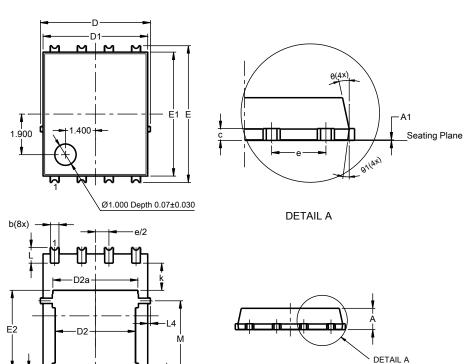
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8 (SWP) (Type UX)

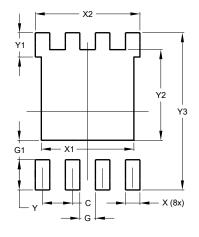


PowerDI5060-8 (SWP)					
(Type UX)					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0	0.05			
b	0.30	0.50	0.41		
b2	0.20	0.35	0.25		
b4).25REF	-		
С	0.230	0.330	0.277		
D	5	.15 BS0)		
D1	4.70	5.10	4.90		
D2	3.56	3.96	3.76		
D2a	3.78	3.98			
E	6	6.40 BSC			
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a	4.195	4.595	4.395		
е	1.27BSC				
k	1.05				
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
L1a	0.050REF				
L4	0.025	0.225	0.125		
M	3.205	4.005	3.605		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8 (SWP) (Type UX)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
X	0.610		
X1	4.100		
X2	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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